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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Tv

11/28/05

In re application of:  
Fu-Hsin Chen

Serial No.: 10/801,234

Filed: March 16, 2004

For: HIGH-VOLTAGE MOS TRANSISTOR  
AND METHOD FOR FABRICATING  
THE SAME

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Attorney Docket No. 24061.79  
(TSMC2003-0322)

Customer No. 42717

Group Art Unit: 2826

Examiner: Dickey, Thomas L.

**RESPONSE AFTER FINAL OFFICE ACTION**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In response to the Final Office Action mailed September 28, 2005, please reconsider the application in light of the following remarks:

**A Listing of the Claims** begins on page 2 of this paper.

**Remarks** begin on page 5 of this paper.